imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

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MBRT60045 thru MBRT600100R

Silicon Power Schottky Diode

Features

- High Surge Capability
- Types up to 100 V V_{RRM}
- Isolation Type Package

 $V_{RRM} = 20 V - 100 V$ I_F = 600 A

Three Tower Package



Maximum ratings, at T_i = 25 °C, unless otherwise specified ("R" devices have leads reversed)

Parameter	Symbol	Conditions	MBRT60045 (R) MBRT60060 (R)) MBRT60080 (I	R) MBRT600100 (R	ł) Unit
Repetitive peak reverse voltage	V _{RRM}		45	60	80	100	V
RMS reverse voltage	V_{RMS}		32	42	57	70	V
DC blocking voltage	V_{DC}		45	60	80	100	V
Continuous forward current	I _F	T _C ≤ 100 °C	600	600	600	600	А
Surge non-repetitive forward current, Half Sine Wave	$I_{F,SM}$	$T_{\rm C}$ = 25 °C, $t_{\rm p}$ = 8.3 ms	4000	4000	4000	4000	А
Operating temperature	Tj		-40 to 150	-40 to 150	-40 to 150	-40 to 150	°C
Storage temperature	T _{stg}		-40 to 175	-40 to 175	-40 to 175	-40 to 175	°C

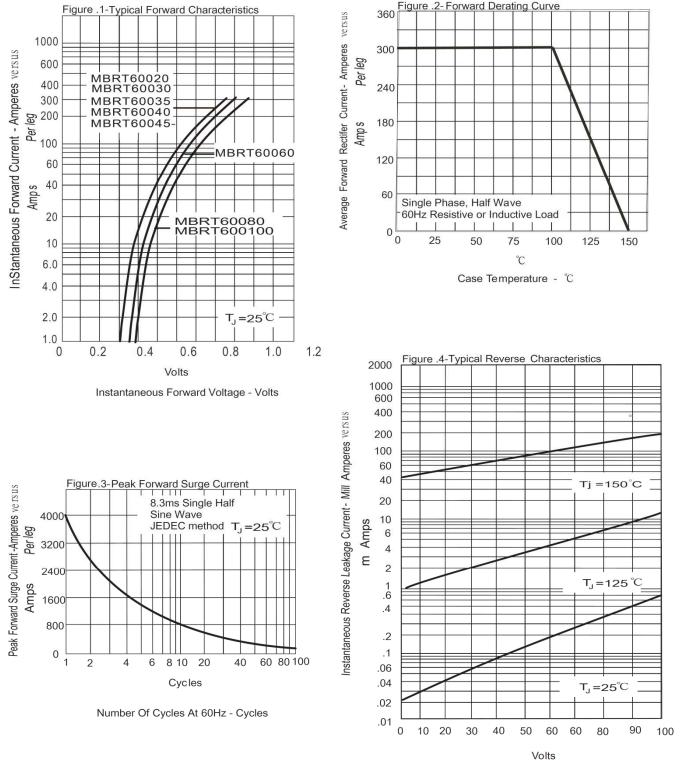
Electrical characteristics, at Tj = 25 °C, unless otherwise specified

Parameter	Symbol	Conditions	MBRT60045 (R)	MBRT60060(R)	MBRT60080 (R)	MBRT600100	(R) Unit
Diode forward voltage	V _F	I _F = 300 A, T _j = 25 °C	0.75	0.8	0.88	0.88	V
Reverse current	I _R	V _R = 20 V, T _i = 25 °C	1	1	1	1	mA
		V _R = 20 V, T _j = 125 °C	20	20	20	20	
Thermal characteristics							
Thermal resistance, junction -	R_{thJC}		0.12	0.12	0.12	0.12	°C/W
case							





MBRT60045 thru MBRT600100R



Reverse Voltage - Volts(%)

